

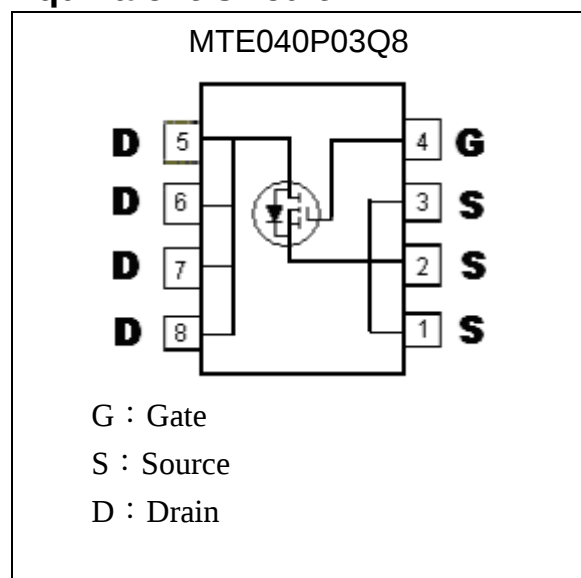
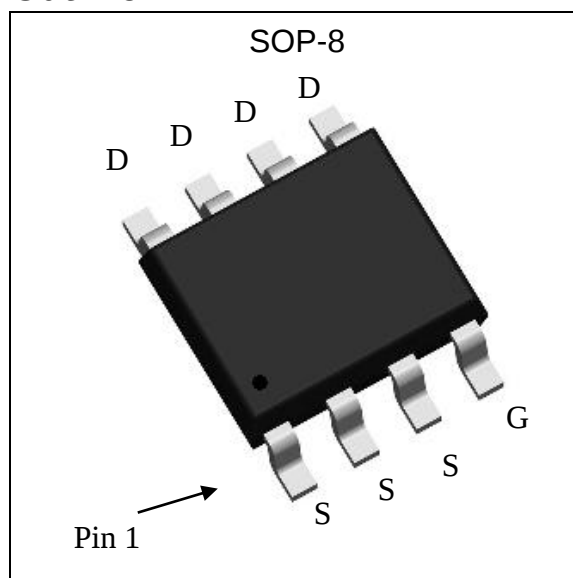
P-Channel Enhancement Mode MOSFET

MTE040P03Q8

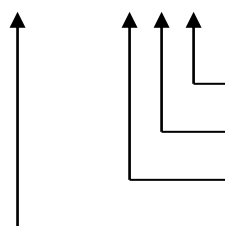
BV_{DSS}	-30V
$I_D@V_{GS}=-10V, T_A=25^{\circ}C$	-6.6A
$I_D@V_{GS}=-10V, T_A=70^{\circ}C$	-5.3A
$R_{DS(on)}@V_{GS}=-10V, I_D=-5.3A$	36.3m Ω (typ)

Features

- Simple drive requirement
- Low on-resistance
- Fast switching speed
- Pb-free lead plating and halogen-free package

Equivalent Circuit

Outline

Ordering Information

Device	Package	Shipping
MTE040P03Q8-0-T3-G	SOP-8 (Pb-free lead plating and halogen-free package)	2500 pcs/ Tape & Reel



Environment friendly grade : S for RoHS compliant products, G for RoHS compliant and green compound products
Packing spec, T3 : 2500 pcs / tape & reel, 13" reel
Product rank, zero for no rank products
Product name

**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	-30	V
Gate-Source Voltage	V _{GS}	±25	
Continuous Drain Current @ V _{GS} =-10V, T _A =25°C (Note 1)	I _D	-6.6	A
Continuous Drain Current @ V _{GS} =-10V, T _A =70°C (Note 1)		-5.3	
Pulsed Drain Current (Note 2)	I _{DM}	-36	
Avalanche Current @ L=0.1mH	I _{AS}	-20	
Avalanche Energy @ L=1mH, I _D =-6.6A, V _{DD} =-15V	E _{AS}	21	mJ
Total Power Dissipation (Note 1)	P _D	T _A =25 °C 3.1	W
		T _A =70 °C 2	
Operating Junction and Storage Temperature	T _j , T _{stg}	-55~+150	°C

Note : 1.Surface mounted on FR-4 board, t≤10sec.

2.Pulse width ≤300μs, Duty Cycle≤2%

Thermal Data

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-case, max	R _{θJC}	25	°C/W
Thermal Resistance, Junction-to-ambient, max	R _{θJA}	40 (Note)	

Note : Surface mounted on 1 in² copper pad of FR-4 board, pulse width≤10s.**Electrical Characteristics** (T_j=25°C, unless otherwise specified)

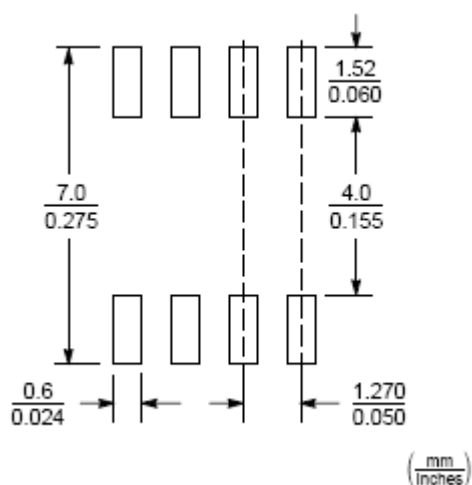
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	-30	-	-	V	V _{GS} =0V, I _D =-250μA
V _{GS(th)}	-1.5	-	-3.5		V _{DS} =V _{GS} , I _D =-250μA
I _{GSS}	-	-	±100	nA	V _{GS} =±25V, V _{DS} =0V
I _{DSS}	-	-	-1	μA	V _{DS} =-24V, V _{GS} =0V
	-	-	-5		V _{DS} =-24V, V _{GS} =0V, T _j =55°C
*R _{DS(ON)}	-	36.3	48	mΩ	I _D =-5.3A, V _{GS} =-10V
*G _{FS}	-	5	-	S	V _{DS} =-10V, I _D =-5A
Dynamic					
C _{iss}	-	484	-	pF	V _{DS} =-25V, V _{GS} =0V, f=1MHz
C _{oss}	-	65	-		
C _{rss}	-	51	-		
*t _{d(ON)}	-	7.2	-	ns	V _{DD} =-15V, I _D =-5.3A, V _{GS} =-10V, R _G =1Ω
*t _r	-	15.8	-		
*t _{d(OFF)}	-	33	-		
*t _f	-	12.8	-		
*Q _g	-	10.6	-	nC	V _{DS} =-24V, V _{GS} =-10V, I _D =-5.3A
*Q _{gs}	-	2.6	-		
*Q _{gd}	-	2.9	-		



Source Drain Diode					
*V _{SD}	-	-0.81	-1.2	V	V _{GS} =0V, I _S =-1.7A
trr	-	8	-	ns	I _F =-1.7A, dI _F /dt=100A/μs
Q _{rr}	-	3.2	-	nC	

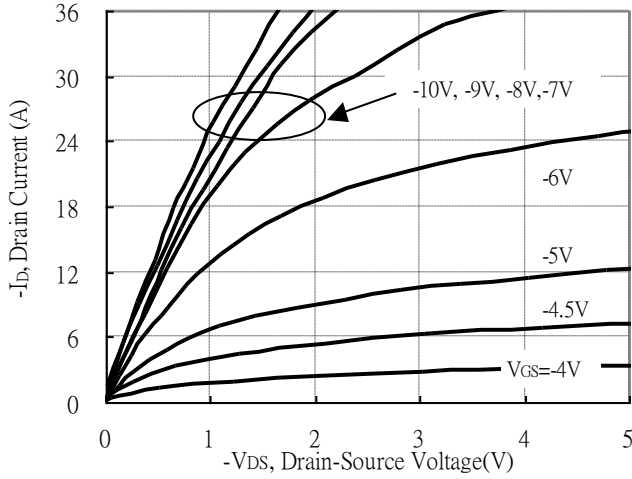
*Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

Recommended Soldering Footprint

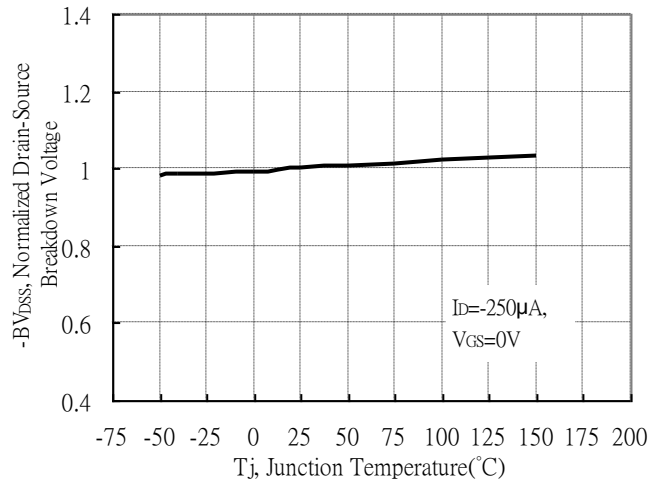


Typical Characteristics

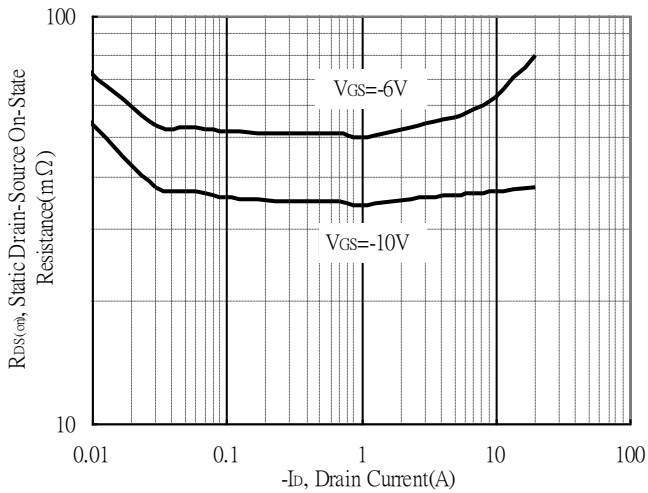
Typical Output Characteristics



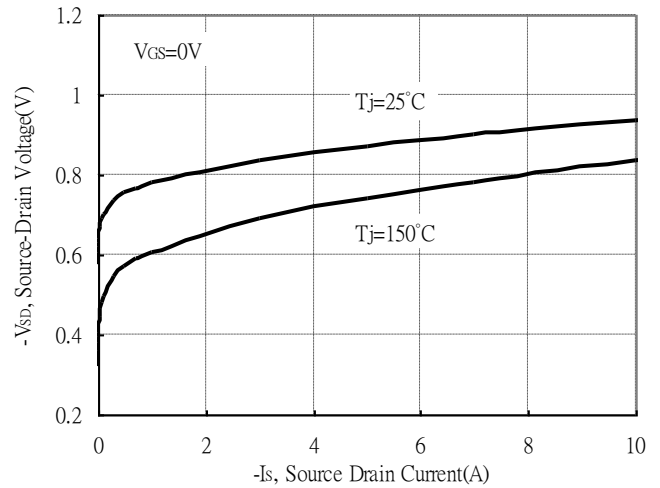
Breakdown Voltage vs Ambient Temperature



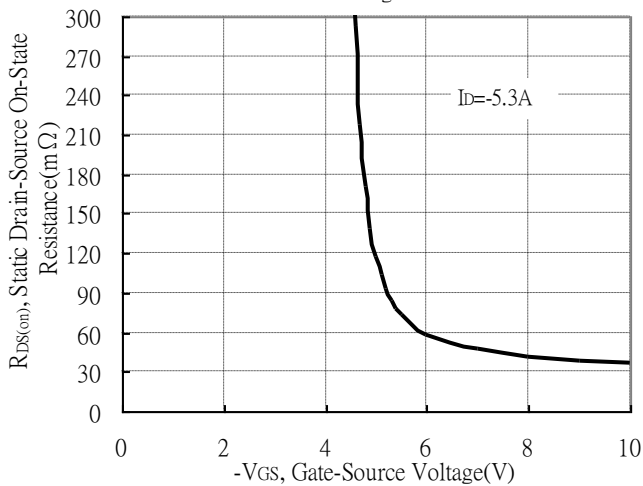
Static Drain-Source On-State resistance vs Drain Current



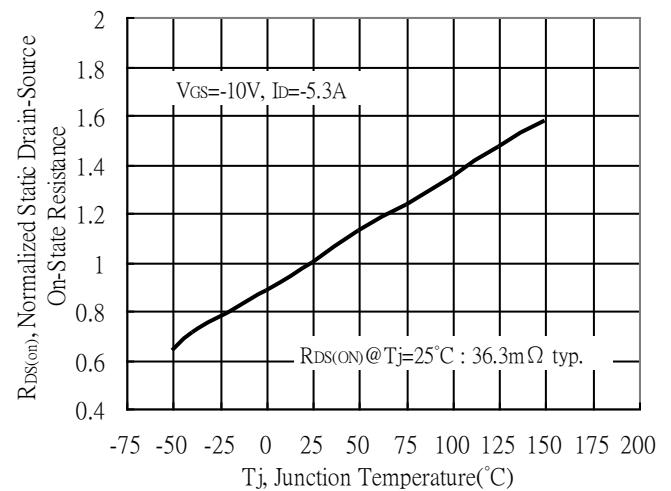
Source Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

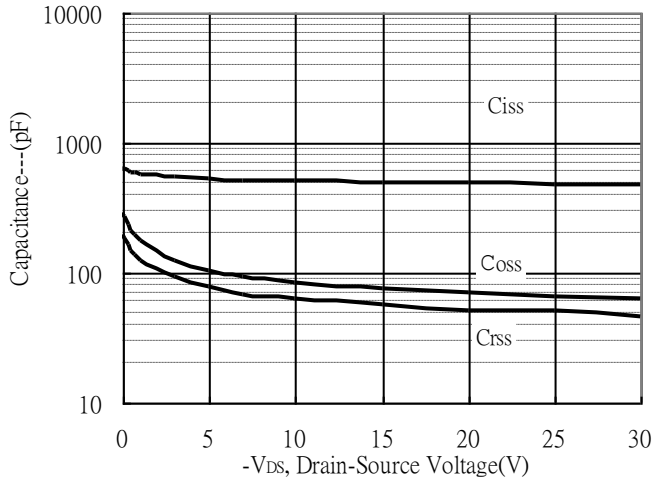


Drain-Source On-State Resistance vs Junction Temperature

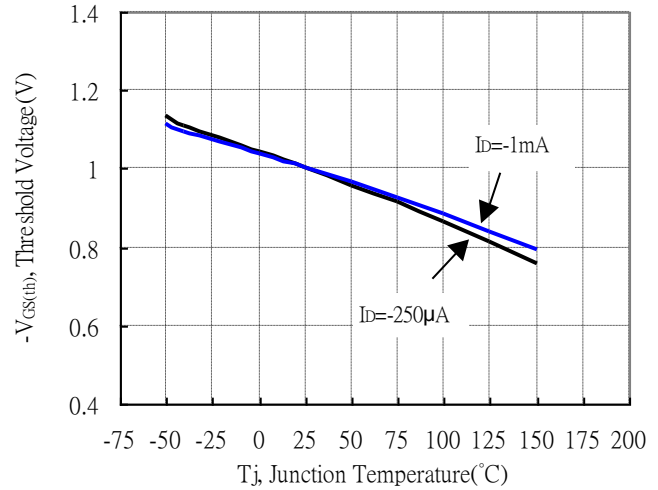


Typical Characteristics(Cont.)

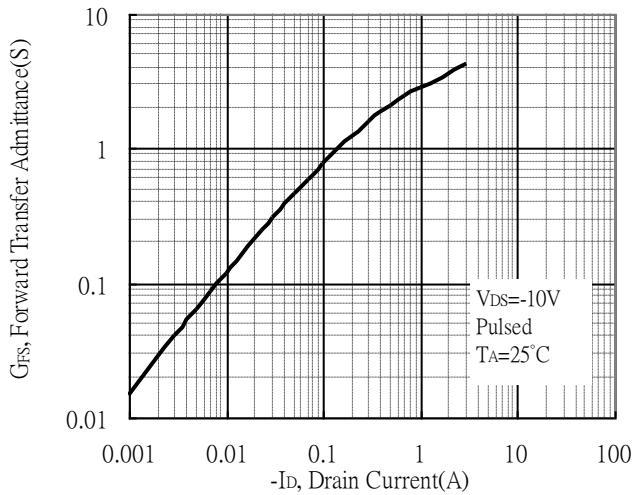
Capacitance vs Drain-to-Source Voltage



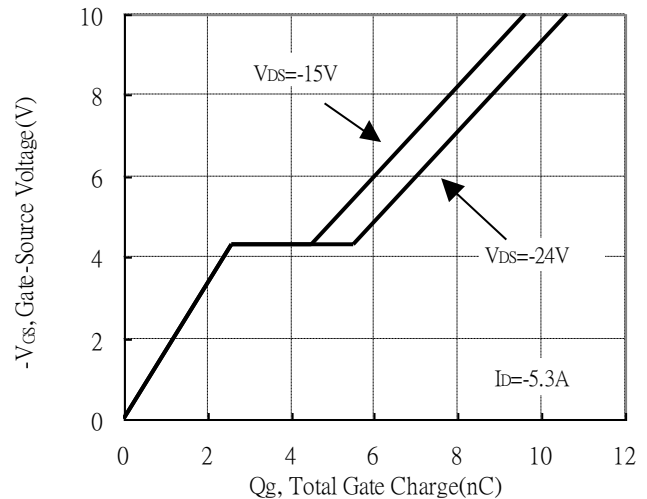
Threshold Voltage vs Junction Temperature



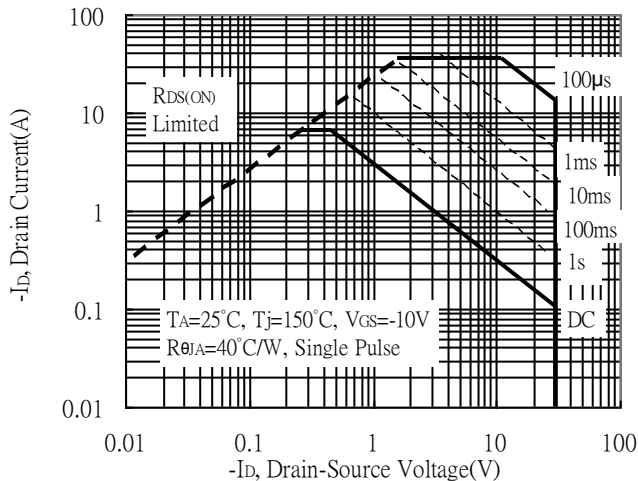
Forward Transfer Admittance vs Drain Current



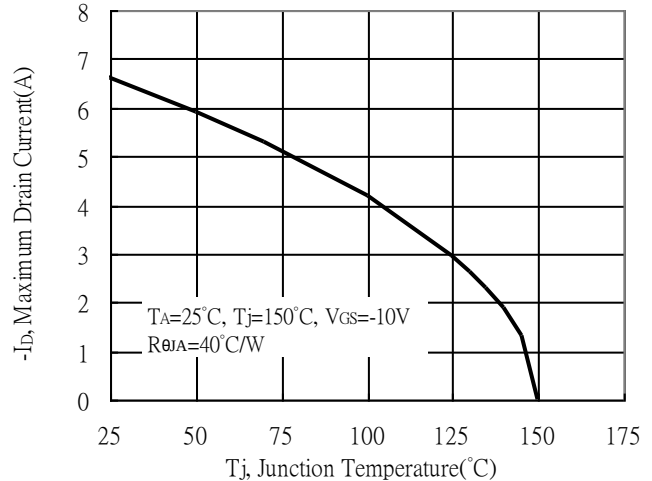
Gate Charge Characteristics



Maximum Safe Operating Area

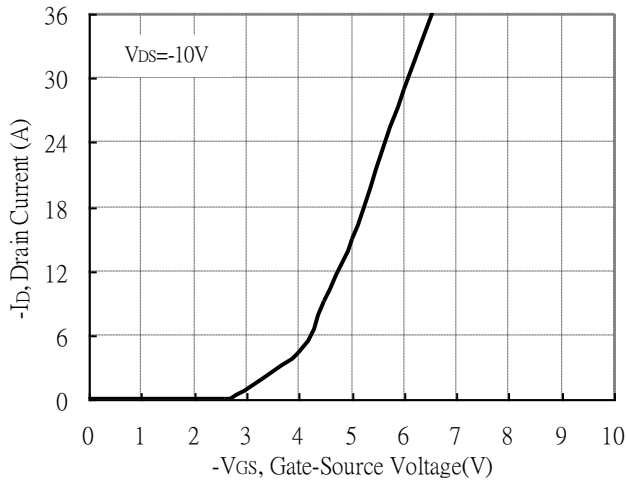


Maximum Drain Current vs Junction Temperature

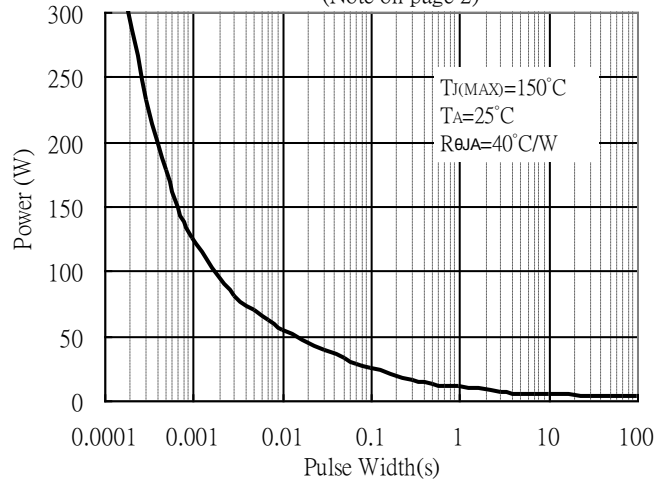


Typical Characteristics(Cont.)

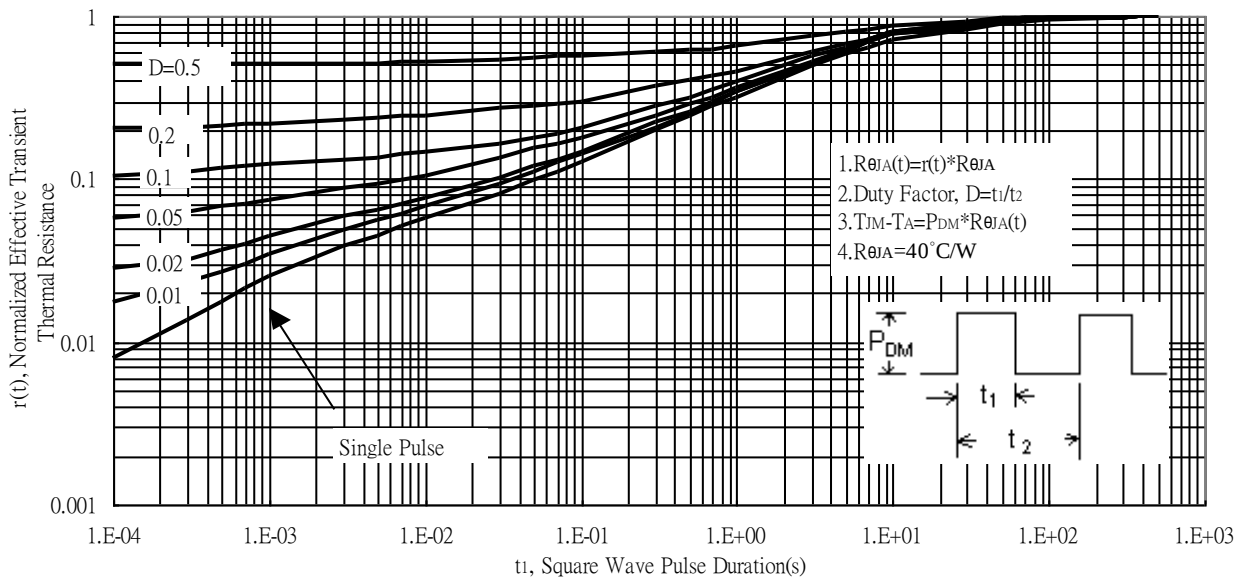
Typical Transfer Characteristics



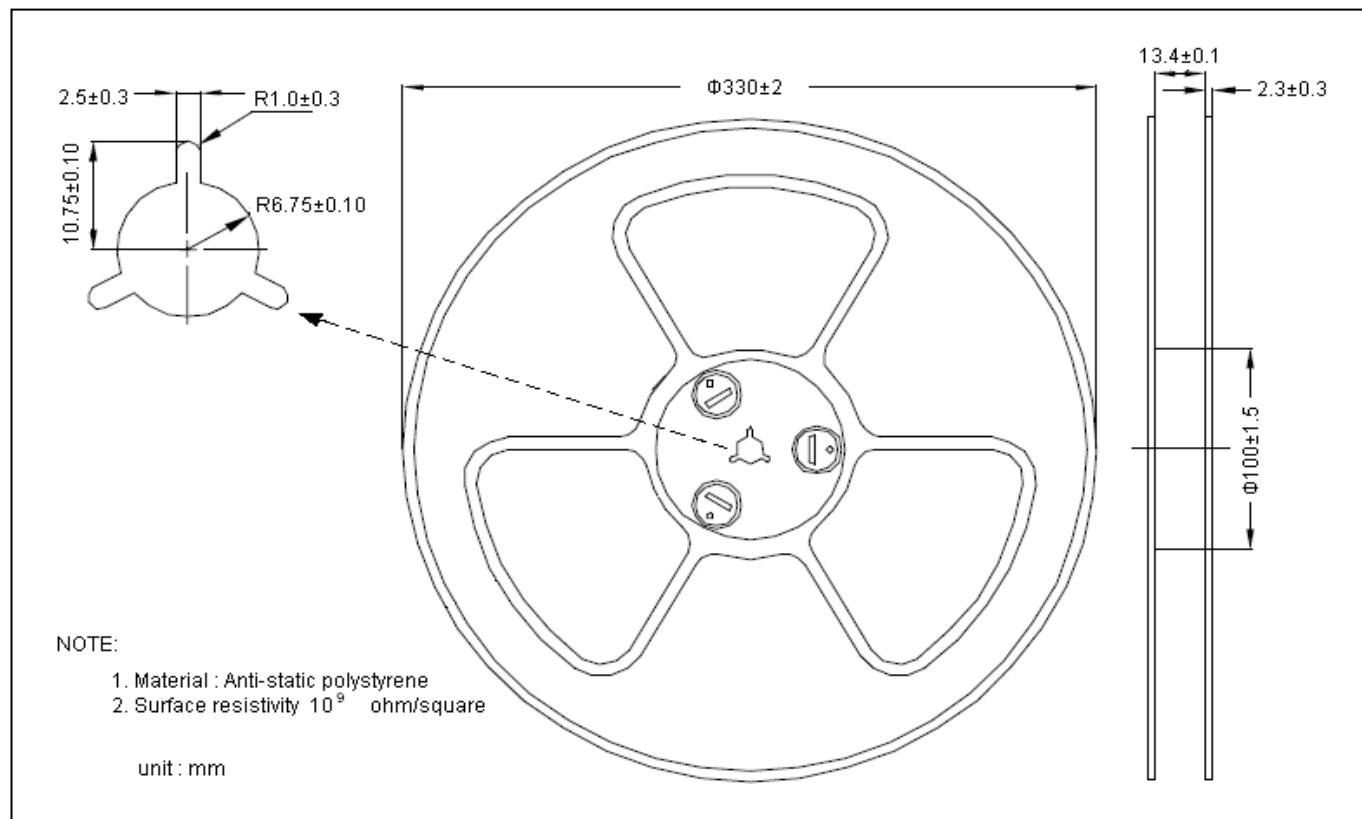
Single Pulse Power Rating, Junction to Ambient
(Note on page 2)



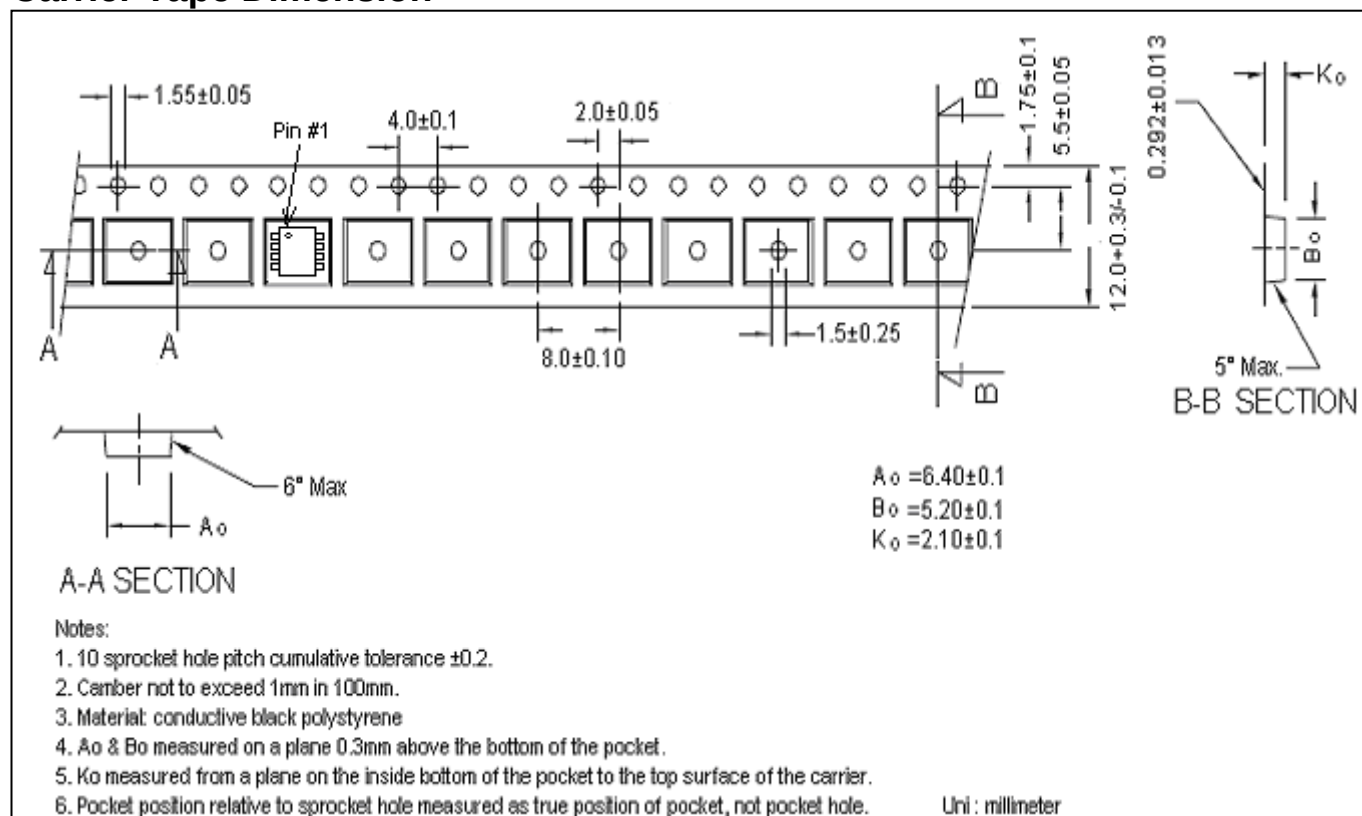
Transient Thermal Response Curves



Reel Dimension



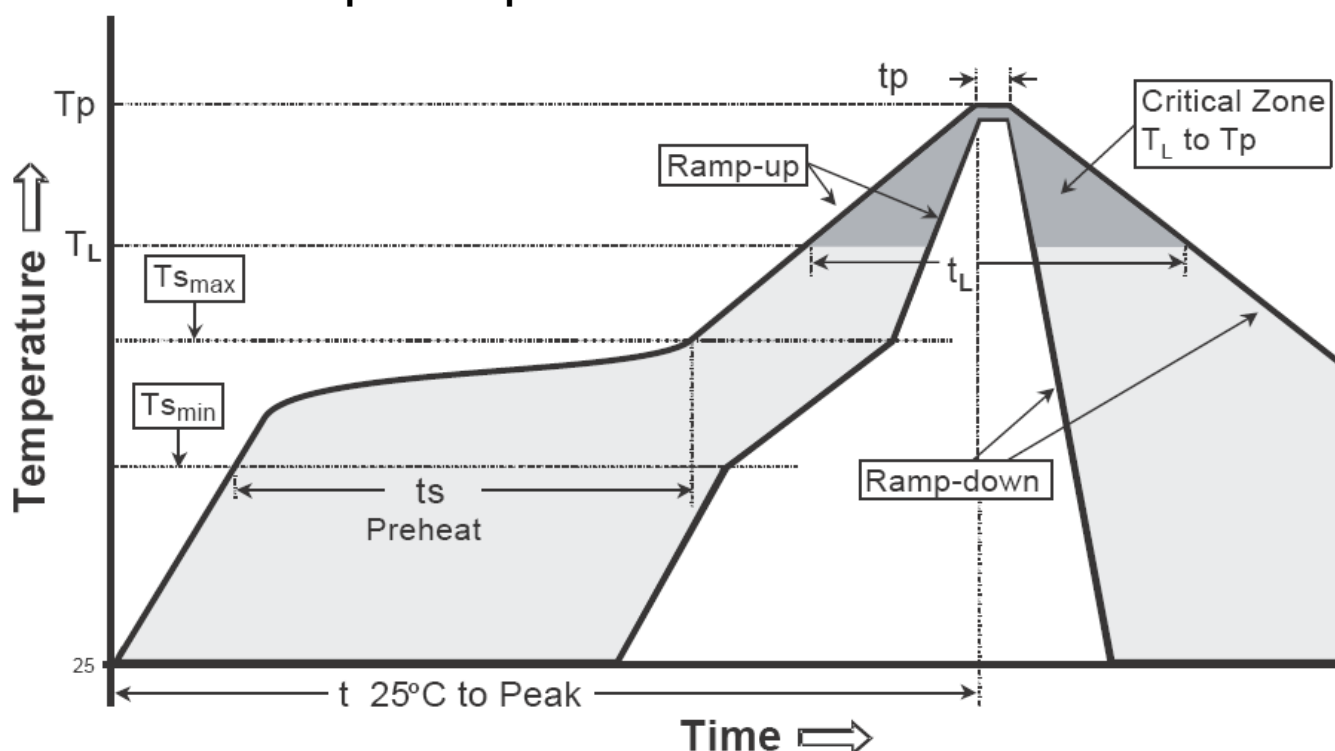
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

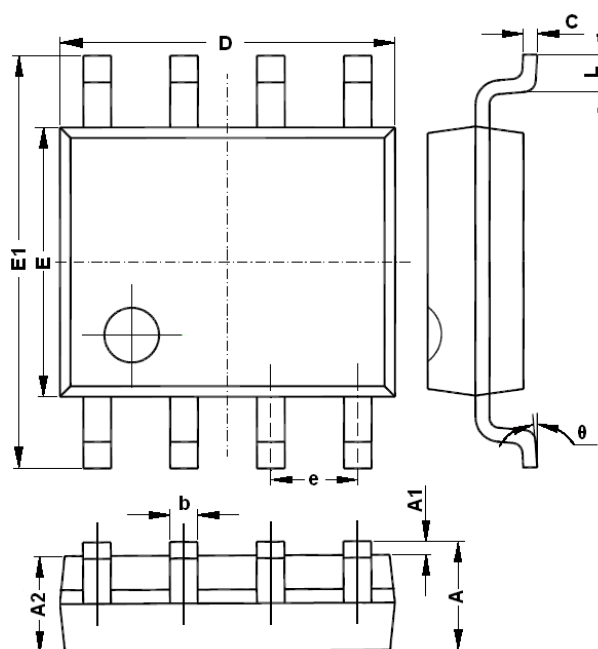
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(Ts min) -Temperature Max(Ts max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (Tl) - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(Tp)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOP-8 Dimension



Marking:

Device Name

E040

Date Code

P03

Date Code(counting from left to right) :

1st code: year code, the last digit of Christian year

2nd code : month code, Jan→A, Feb→B, Mar→C, Apr→D

May→E, Jun→F, Jul→G, Aug→H, Sep→J,

Oct→K, Nov→L, Dec→M

3rd and 4th codes : production serial number, 01~99

8-Lead SOP-8 Plastic Package
CYStek Package Code: Q8

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069	E	3.800	4.000	0.150	0.157
A1	0.100	0.250	0.004	0.010	E1	5.800	6.200	0.228	0.244
A2	1.350	1.550	0.053	0.061	e	1.270	(BSC)	0.050	(BSC)
b	0.330	0.510	0.013	0.020	L	0.400	1.270	0.016	0.050
c	0.170	0.250	0.006	0.010	θ	0	8°	0	8°
D	4.700	5.100	0.185	0.200					

Notes: 1. Controlling dimension: millimeters.

2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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